

250132US-2TTCRD DIV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: :
SHIHO OKUNO, ET AL. : GROUP UNIT:
SERIAL NO: NEW DIV. APPLN. :
FILED: HEREWITH : EXAMINER:
FOR: MAGNETORESISTANCE EFFECT :
ELEMENT, ITS MANUFACTURING
METHOD, MAGNETIC REPRODUCING
ELEMENT AND MAGNETIC MEMORY

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to initial examination on the merits, please amend the above-identified
application as follows:

Amendments to the Specification begin on page 2 of this paper

Listing of the Claims begins on page 3 of this paper.

Remarks begin on page 5 of this paper.